# NHC-stabilized Parent Arsanylalanes and -gallanes 

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#### Abstract

The synthesis and characterization of the unprecedented compounds IDipp $\cdot E^{\prime} \mathrm{H}_{2} A s H_{2} \quad\left(E^{\prime}=A l, G a ;\right.$ IDipp $=$ 1,3-bis(2,6-diisopropylphenyl)imidazolin-2-ylidene) are reported, the first monomeric, parent representatives of an arsanylalane and arsanylgallane, respectively, stabilized only by a $L B$ ( $L B=$ Lewis Base). They are prepared by a salt metathesis reaction of $\mathrm{KAsH}_{2}$ with IDipp $\cdot E^{\prime} \mathrm{H}_{2} \mathrm{Cl}\left(E^{\prime}=\mathrm{Al}\right.$, $\mathrm{Ga})$. The $\mathrm{H}_{2}$-elimination pathway through the reaction of $\mathrm{AsH}_{3}$ with IDipp $\cdot E^{\prime} H_{3}\left(E^{\prime}=A l, G a\right)$ was found to be a possible synthetic route with some disadvantages compared to the salt metathesis reaction. The corresponding organo-substituted compounds IDipp•GaH2 $\mathrm{AsPh}_{2}$ (1) and IDipp• $\mathrm{AlH}_{2} \mathrm{AsPh} 2_{2}$ (2) were obtained by the reaction of KAsPh with IDip$p \cdot E^{\prime} \mathrm{H}_{2} \mathrm{Cl}\left(E^{\prime}=\mathrm{Al}, \mathrm{Ga}\right)$. The novel branched parent compounds IDipp $\cdot E^{\prime} H\left(E H_{2}\right)_{2} \quad\left(E^{\prime}=A l, \quad G a ; E=P\right.$, As) were synthesized by salt metathesis reactions starting from IDipp $\cdot E^{\prime} H C l_{2}\left(E^{\prime}=A l\right.$, Ga). Supporting DFT computations give insight into the different synthetic pathways and the stability of the products.


## Introduction

The chemistry of group 13/15 compounds is an active research field and has influenced many areas of chemistry. For instance, unsaturated compounds of the type $\mathrm{H}_{2} \mathrm{E}^{\prime} \mathrm{EH}_{2}\left(\mathrm{E}^{\prime}=\right.$ Group 13 element, $\mathrm{E}=$ Group 15 element) are isoelectronic to alkenes. They are of interest as starting materials for semiconducting applications ${ }^{[1]}$ or as precursor for composite 13/15 materials. ${ }^{[2]}$ In comparison to aminoboranes $\mathrm{LB} \cdot \mathrm{BR}_{2} \mathrm{NR}_{2} \cdot \mathrm{LA}(\mathrm{LB}=$ Lewis base, $\mathrm{LA}=$ Lewis acid) the

[^0]chemistry of the heavier group $13 / 15$ element analogs is rarely investigated. The few known compounds of arsanylalanes and -gallanes LB•[ $\left.\mathrm{E}^{\prime} \mathrm{R}_{2} \mathrm{AsR}_{2}\right]_{n} \cdot \mathrm{LA}\left(\mathrm{E}^{\prime}=\mathrm{Al}, \mathrm{Ga}\right)$ exist as dimers (A, $n=2),{ }^{[3]}$ trimers $(n=3),{ }^{[4]}$ or LB/LA-stabilized monomers depending on the steric demands of the organic substituents ${ }^{[5]}$ (B, Figure 1) as well as the LA/LB. Since these compounds are precursors for the synthesis of binary GaAs or AlAs materials via MOCVD processes (metalorganic chemical vapor deposition), ${ }^{[6]}$ the parent compounds of these precursors are of particular interest for improving the current MOCVD process which involves the reaction of trimethylgallium with the toxic gas $\mathrm{AsH}_{3}$ at elevated temperatures. In contrast to the phosphorus analog $\mathrm{E}^{\prime} \mathrm{H}_{2} \mathrm{PH}_{2}\left(\mathrm{E}^{\prime}=\mathrm{Al}, \mathrm{Ga}\right)$, for which we recently succeeded in the synthesis of the first only LBstabilized parent compounds IDipp• $\cdot \mathrm{E}^{\prime} \mathrm{H}_{2} \mathrm{PH}_{2}\left(\mathrm{E}^{\prime}=\mathrm{Al}, \mathrm{Ga}\right.$; IDipp $=1,3$-bis(2,6-diisopropylphenyl)imidazolin-2-yli-
dene) ${ }^{[7]}$ the heavier arsenic analogs exhibit a higher lability of the $\mathrm{Ga}-\mathrm{As} / \mathrm{Al}-\mathrm{As}$ bond, which is why they have so far only been studied by theoretical methods. ${ }^{[8]}$ In fact, because of their toxicity, light sensitivity, and tendency to decompose, as well as the unsuitable NMR activity of the As nucleus, the handling and characterization of such compounds are hampered by numerous difficulties. Moreover, only a few examples of stable primary arsines, such as $\left(2,6-\mathrm{Tipp}_{2} \mathrm{C}_{6} \mathrm{H}_{3}\right) \mathrm{AsH}_{2}$ (Tipp $=2,4,6-i \mathrm{Pr}_{3} \mathrm{C}_{6} \mathrm{H}_{2}$ ), TriptAsH ${ }_{2} \quad$ (Tript $=$ tribenzobarrelene), ${ }^{[9]}$ or $\mathrm{NMe}_{3} \cdot \mathrm{BH}_{2} \mathrm{AsH}_{2}{ }^{[10 a]}$ containing bulky or special substituents have so far been reported. Therefore, the question arises whether compounds containing $\mathrm{AsH}_{2}$ bound to alanes and gallanes can be synthesized. In any case, a stabilization via a LB and a LA or at least via a LB alone would be needed if organic substitution at the As and the Al and Ga atoms, respectively, was to be avoided. Even from this perspective, it is astonishing that only parent arsanylboranes exist as LA/LB- ${ }^{[106]}$ or LB-stabilized ${ }^{[10 a]}$ molecules. No LA/ LB-stabilized arsanylalanes or -galanes have been reported yet, only their phosphanyl analogs, ${ }^{[10 c]}$ which reflects the


A

B

c

IDipp $=1,3$-bis(2,6-diisopropylphenyl)-imidazolin-2-ylidene
$\mathrm{E}^{\prime}=\mathrm{Al}, \mathrm{Ga}$
$R=H, P h$
Figure 1. Examples of dimeric (A) and monomeric arsanyltrielanes (B and C).
specific lability of the corresponding $\mathrm{E}^{\prime}-\mathrm{As}$ bonds $\left(\mathrm{E}^{\prime}=\mathrm{Al}\right.$, Ga).

Herein, we report the synthesis and characterization of the first monomeric parent compound of an arsanylgallane, IDipp• $\mathrm{GaH}_{2} \mathrm{AsH}_{2}$ (3), and an arsanylalane, IDipp $\cdot \mathrm{AlH}_{2} \mathrm{AsH}_{2}$ (4), as well as their organo-substituted analogs IDipp• $\mathrm{E}^{\prime}$ $\mathrm{H}_{2} \mathrm{AsPh}_{2}\left(\mathbf{1}: \mathrm{E}^{\prime}=\mathrm{Ga}, \mathbf{2}: \mathrm{E}^{\prime}=\mathrm{Al} ; \mathbf{C}\right)$, only stabilized by a LB. The initially formed unprecedented side products IDipp•E'H$\left(\mathrm{EH}_{2}\right)_{2}\left(\mathrm{E}^{\prime}=\mathrm{Al}, \mathrm{Ga} ; \mathrm{E}=\mathrm{As}, \mathrm{P} ; 5-\mathbf{8}\right)$ could be synthesized and characterized on a selective route.

## Results and Discussion

The organo-substituted compounds IDipp• $\mathrm{GaH}_{2} \mathrm{AsPh}_{2}(\mathbf{1})$ and IDipp $\cdot \mathrm{AlH}_{2} \mathrm{AsPh}_{2}$ (2) can be synthesized by the reaction of IDipp $\cdot \mathrm{E}^{\prime} \mathrm{H}_{2} \mathrm{Cl}\left(\mathrm{E}^{\prime}=\mathrm{Ga}, \mathrm{Al}\right)^{[11]}$ with $\mathrm{KAsPh}_{2} \cdot$ dioxane in $\mathrm{Et}_{2} \mathrm{O}$ at $-80^{\circ} \mathrm{C}$ [Eq. (1)]. Compound $\mathbf{1}$ was isolated at $-30^{\circ} \mathrm{C}$ as colorless crystals in a yield of $63 \%$ and $\mathbf{2}$ as pale yellow blocks in a yield of $52 \%$.


In the solid state, $\mathbf{1}$ and $\mathbf{2}$ can be stored at ambient temperatures in an inert atmosphere for more than two months without decomposition. The molecular ion peak of $\mathbf{1}$ is detected at $\mathrm{m} / \mathrm{z} 688.2142$ in the mass spectrum (LIFDIMS). The LIFDI-MS spectrum of $\mathbf{2}$ shows a fragment peak of IDipp $^{+}$due to decomposition of $\mathbf{2}$ during the ionization process. The ${ }^{1} \mathrm{H}$ NMR spectra of $\mathbf{1}$ and $\mathbf{2}$ show a broad singlet at $\delta=4.28 \mathrm{ppm}$ for the $\mathrm{GaH}_{2}$ moiety in $\mathbf{1}$ and a broad singlet at $\delta=3.95 \mathrm{ppm}$ for the $\mathrm{AlH}_{2}$ moiety in 2, respectively. The ${ }^{27} \mathrm{Al}$ NMR spectrum of 2 reveals a broad singlet at $\delta=$ 126.5 ppm , which partially overlays with the signal of the NMR sample head and the NMR tube material.

The structures of $\mathbf{1}$ and $\mathbf{2}$, determined by single-crystal Xray analysis, are depicted in Figure 2 and Figure S35 (cf. SI), respectively. The $\mathrm{Al}-\mathrm{As}$ bond in 2 shows a length of 2.4929 (4) $\AA$ and is therefore slightly longer than the $\mathrm{Al}-\mathrm{As}$ bond $(2.485(2) \AA)$ in $\mathrm{tmp}_{2} \mathrm{AlAsPh}_{2}{ }^{[12]}$ (tmp $=2,2,6,6$-tetramethylpiperidine). Compound $\mathbf{1}$ reveals a $\mathrm{Ga}-$ As bond length of $2.4659(5) \AA$, which is in good agreement with the sum of the covalent radii $(2.46 \AA)$ of Ga and As. ${ }^{[13]}$ Compared to the few other known examples of monomeric arsanylgallanes, the $\mathrm{Ga}-\mathrm{As}$ bond in $\mathbf{1}$ is slightly longer than in $\left(\mathrm{C}_{5} \mathrm{Me}_{5}\right)_{2} \mathrm{GaAs}-$ $\left(\mathrm{SiMe}_{3}\right)_{2}(2.433 \AA)^{[5 \mathrm{sa}]}$ and similar to $\left(\mathrm{Mes}_{2} \mathrm{As}\right)_{3} \mathrm{Ga}(2.433-$ $2.508 \AA)^{[14]}$ and $(t-\mathrm{Bu})_{2} \mathrm{GaAs}(t-\mathrm{Bu})_{2}(2.466 \AA) .{ }^{[5]]}$ In contrast, dimeric structures of the type $\left[\mathrm{R}_{2} \mathrm{GaAsR}^{\prime}\right]_{2}$ feature larger $\mathrm{Ga}-\mathrm{As}$ bond lengths of $2.558,2.550$, and $2.524 \AA$ in $[n-$


Figure 2. Molecular structure of 1 in the solid state; thermal ellipsoids at $50 \%$ probability. ${ }^{[19]}$ Selected bond lengths [ $[\AA]$ and angles [ ${ }^{\circ}$ ]: Ga-As 2.4659(5), Ga-C1 2.068(3), C1-Ga-As 109.33(8), H1-Ga-As-C4 134.4(1).
$\left.\mathrm{Bu}_{2} \mathrm{GaAs}(t-\mathrm{Bu})_{2}\right]_{2},{ }^{[15]}\left[\mathrm{Me}_{2} \mathrm{GaAs}(t-\mathrm{Bu})_{2}\right]_{2},{ }^{[15]}$ and $\left[\mathrm{Ph}_{2} \mathrm{GaAs}-\right.$ $\left.\left(\mathrm{CH}_{2} \mathrm{SiMe}_{3}\right)_{2}\right]_{2}{ }^{[4]}$ respectively. These larger $\mathrm{Ga}-\mathrm{As}$ distances are not the result of the tetracoordination of the Ga atom or the ring formation, since the trimer $\left[\mathrm{Br}_{2} \mathrm{GaAs}\left(\mathrm{CH}_{2} \mathrm{SiMe}_{2}\right)_{2}\right]_{3}$ exhibits shorter $\mathrm{Ga}-\mathrm{As}$ bond lengths of 2.432(2)-2.464(1) $\AA$. A more plausible explanation is the steric repulsion and the ring strain due to endocyclic bond angles of $83-96^{\circ}$ in the dimers in contrast to $103-121^{\circ}$ in the trimer $\left[\mathrm{Br}_{2} \mathrm{GaAs}\right.$ $\left.\left(\mathrm{CH}_{2} \mathrm{SiMe}_{2}\right)_{2}\right]_{3}$.

Compounds $\mathbf{1}$ and $\mathbf{2}$ reveal an eclipsed conformation with a torsion angle of $\mathrm{H} 1-\mathrm{Ga}-\mathrm{As}-\mathrm{C} 4=134.4^{\circ}$ and $\mathrm{H} 1-\mathrm{Al}-\mathrm{As}-\mathrm{C} 4=$ $138.1^{\circ}$, respectively. The $\mathrm{E}^{\prime}-\mathrm{C} 1$ bond lengths in $\mathbf{1}(2.068(3) \AA$, $\left.\mathrm{E}^{\prime}=\mathrm{Ga}\right)$ and $2\left(2.0634(12) \AA, \mathrm{E}^{\prime}=\mathrm{Al}\right)$ are in the range of usual $\mathrm{E}^{\prime}-\mathrm{C}$ single bonds and are similar to the $\mathrm{Ga}-\mathrm{C} 1$ bond length in IDipp $\cdot \mathrm{GaH}_{2} \mathrm{PCy}_{2}\left(2.090(2) \AA \AA^{[7]} \mathrm{Cy}=\right.$ cyclohexyl) and to the $\mathrm{Al}-\mathrm{C} 1$ (2.056(2) $\AA$ ) bond length in IDipp $\cdot \mathrm{AlH}_{2} \mathrm{PH}_{2}{ }_{2}{ }^{[7]}$ respectively. The $\mathrm{C} 1-\mathrm{Ga}-\mathrm{As}$ angle of $1\left(109.33(8)^{\circ}\right)$ is in good agreement with the C1-Al-As angle in $2\left(109.53(3)^{\circ}\right)$.

For the synthesis of the parent compounds IDipp•Ga$\mathrm{H}_{2} \mathrm{AsH}_{2}$ (3) and IDipp• $\mathrm{AlH}_{2} \mathrm{AsH}_{2}$ (4), two different routes were used [Eq. (2)]. Similarly to the substituted analogs, compounds $\mathbf{3}$ and $\mathbf{4}$ are accessible by a salt metathesis reaction between IDipp• $\mathrm{E}^{\prime} \mathrm{H}_{2} \mathrm{Cl}\left(\mathrm{E}^{\prime}=\mathrm{Al}, \mathrm{Ga}\right)$ and $\mathrm{KAsH}_{2}$ at $-80^{\circ} \mathrm{C}$ in THF (route 1). Furthermore, 3 and $\mathbf{4}$ can be synthesized by $\mathrm{H}_{2}$-elimination reactions of IDipp• $\cdot \mathrm{E}^{\prime} \mathrm{H}_{3}\left(\mathrm{E}^{\prime}=\mathrm{Al}, \mathrm{Ga}\right)$ and $\mathrm{AsH}_{3}$ (route 2). For this purpose, an excess of $\mathrm{AsH}_{3}$ is condensed onto a solution of IDipp• $\mathrm{E}^{\prime} \mathrm{H}_{3}$ in toluene at $-70^{\circ} \mathrm{C}$ and stirred for 3 days at this temperature. Unfortunately, 3 and 4 were formed only in minor amounts via route 2 according to ${ }^{1} \mathrm{H}$ NMR spectroscopic monitoring (Figure S1 and S 2 ). The low yield of these $\mathrm{H}_{2}$-elimination reactions is obviously caused by the applied temperature of $-70^{\circ} \mathrm{C}$, which significantly slows down the exergonic reaction between IDipp $\cdot \mathrm{E}^{\prime} \mathrm{H}_{3}$ and $\mathrm{AsH}_{3}$ but was needed throughout the reaction to keep $\mathrm{AsH}_{3}$ condensed (see below, Table 1, process 1 ). Compound 3 can be isolated at $-30^{\circ} \mathrm{C}$ in a crystalline yield of $39 \%$ via route 1 . In the mass spectrum

Table 1: Thermodynamic characteristics of studied reactions (gas phase compounds if not noted otherwise). ${ }^{[a]}$

| Entry | Process | $\Delta H^{\circ}{ }_{298}$ | $\begin{aligned} & \mathrm{E}^{\prime}=\mathrm{Al} \\ & \Delta \mathrm{~S}^{\circ} \end{aligned}$ | $\Delta G^{\circ}{ }_{298}$ | $\Delta H^{\circ}{ }_{298}$ | $\begin{aligned} & \mathrm{E}^{\prime}=\mathrm{Ga} \\ & \Delta \mathrm{~S}^{\circ}{ }_{298} \end{aligned}$ | $\Delta G^{\circ}{ }_{298}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 1 | IDipp. $\mathrm{E}^{\prime} \mathrm{H}_{3}+$ As $_{3}=\mathrm{H}_{2}+$ IDipp. $\mathrm{E}^{\prime} \mathrm{H}_{2} \mathrm{AsH}_{2}$ | -27.6 | -26.3 | -19.7 | -29.2 | -26.3 | -21.4 |
| 2 | IDipp.E'H ${ }_{3}+$ AsHPh $_{2}=\mathrm{H}_{2}+$ IDipp $\cdot \mathrm{E}^{\prime} \mathrm{H}_{2}$ AsPh ${ }_{2}$ | -11.2 | -61.8 | 7.2 | -15.7 | -60.6 | 2.3 |
| 3 | IDipp.E' $\mathrm{H}_{2} \mathrm{Cl}+\mathrm{KAsH} \mathrm{H}_{2}=\mathrm{KCl}_{(s)}+$ IDipp $\cdot \mathrm{E}^{\prime} \mathrm{H}_{2} \mathrm{AsH}_{2}$ | -227.7 | -179.8 | -174.1 | -261.9 | -182.8 | -207.4 |
| 4 | IDipp $\cdot \mathrm{E}^{\prime} \mathrm{H}_{2} \mathrm{Cl}+\mathrm{KAsPh} 2 \cdot$ dioxane $=\mathrm{KCl}_{(s)}+$ dioxane + IDipp $\cdot \mathrm{E}^{\prime} \mathrm{H}_{2} \mathrm{AsPh}_{2}$ | -97.2 | 98.6 | -126.6 | -134.2 | 96.7 | -163.1 |
| 5 | IDipp. E' $\left.\mathrm{H}_{2} \mathrm{AsH}_{2}=1 / 3\left(\mathrm{E}^{\prime} \mathrm{H}_{2} \mathrm{AsH}\right)_{2}\right)_{3}+$ IDipp | 65.4 | 76.5 | 42.6 | 52.9 | 75.4 | 30.4 |
| 6 | IDipp. $\mathrm{E}^{\prime} \mathrm{H}_{2} \mathrm{AsPh}_{2}=1 / 3\left(\mathrm{E}^{\prime} \mathrm{Ph}_{2} \mathrm{AsH}_{2}\right)_{3}+$ IDipp | 44.5 | 70.3 | 23.6 | 33.8 | 75.1 | 11.4 |
| 7 | IDipp. $\mathrm{E}^{\prime} \mathrm{H}_{2} \mathrm{AsH}_{2}+\mathrm{AsH}_{3}=\mathrm{H}_{2}+$ IDipp. E' $\mathrm{H}\left(\mathrm{AsH}_{2}\right)_{2}$ | -23.0 | -43.3 | -10.1 | -25.4 | -39.0 | -13.8 |
| 8 | IDipp. E' $\mathrm{H}_{2} \mathrm{AsH}_{2}+\mathrm{PH}_{3}=\mathrm{H}_{2}+$ IDipp. E' $\mathrm{H}\left(\mathrm{PH}_{2}\right)_{2}$ | -13.0 | -38.5 | -1.6 | -11.9 | -40.6 | 0.2 |
| 9 | IDipp $\cdot \mathrm{E}^{\prime} \mathrm{HCl}_{2}+2 \mathrm{NaPH}_{2}=2 \mathrm{NaCl}_{(\mathrm{s})}+\mathrm{IDipp} \cdot \mathrm{E}^{\prime}\left(\mathrm{PH}_{2}\right)_{2}$ | -468.6 | -354.8 | -362.8 | -536.0 | -343.8 | -433.5 |
| 10 | IDipp $\cdot \mathrm{E}^{\prime} \mathrm{HCl}_{2}+2 \mathrm{KAsH}_{2}=2 \mathrm{KCl}{ }_{(s)}+\mathrm{IDipp} \cdot \mathrm{E}^{\prime}\left(\mathrm{AsH}_{2}\right)_{2}$ | -461.8 | -367.9 | -352.1 | -535.9 | -352.9 | -430.7 |

[a] Standard enthalpies $\Delta H^{\circ}{ }_{298}$ and standard Gibbs energies $\Delta \mathrm{G}^{\circ}{ }_{298}$ in $\mathrm{kJ} \mathrm{mol}^{-1}$, standard entropies $\Delta \mathrm{S}^{\circ}{ }_{298}$ in J mol ${ }^{-1} \mathrm{~K}^{-1}$. B3LYP/def2-TZVP level of theory.
(LIFDI-MS) the molecular ion peak of $\mathbf{3}$ is detected at $m / z 535.1239[M-H]^{+}$. The ${ }^{1} \mathrm{H}$ NMR spectrum of $\mathbf{3}$ in $\mathrm{C}_{6} \mathrm{D}_{6}$ shows a triplet at $\delta=-0.18 \mathrm{ppm}\left({ }^{3} J_{\mathrm{H}, \mathrm{H}}=3.68 \mathrm{~Hz}\right)$ for the $\mathrm{AsH}_{2}$ moiety and a broad singlet at $\delta=4.31 \mathrm{ppm}$ for the $\mathrm{GaH}_{2}$ moiety. Compound $\mathbf{3}$ co-crystallizes with the starting material IDipp $\cdot \mathrm{GaH}_{2} \mathrm{Cl}$ (for more information see SI). The structure of 3 in solid state is shown in Figure 3. With a distance of 2.4503(12) $\AA$ the $\mathrm{Ga}-$ As bond length in $\mathbf{3}$ is between the $\mathrm{Ga}-$ As bond lengths in $\mathbf{1}(2.4659(5) \AA),\left(\mathrm{C}_{5} \mathrm{Me}_{5}\right)_{2} \mathrm{GaAs}\left(\mathrm{SiMe}_{3}\right)_{2}$ $(2.433 \AA),^{[5 a]}$ and $(t-\mathrm{Bu})_{2} \mathrm{GaAs}(t-\mathrm{Bu})_{2}(2.466 \AA){ }^{[5 b]}$ The $\mathrm{Ga}-$ C1 bond in $\mathbf{3}(2.0476(17) \AA)$ is shorter compared to the $\mathrm{Ga}^{-}$ C1 distance in 1 (2.068(3) Å) which reveals the repulsion between the NHC and the phenyl groups in 1. Since the $H$ substituents at the As atom had to be restrained, no statement about the conformation of $\mathbf{3}$ can be made. The C1-Ga-As angle in $\mathbf{3}\left(107.99(6)^{\circ}\right)$ is slightly smaller compared to the substituted analog $1\left(109.35(3)^{\circ}\right)$ and to the phosphorus derivative IDipp. $\mathrm{GaH}_{2} \mathrm{PH}_{2}\left(109.19(5)^{\circ}\right) .{ }^{[7]}$

IDipp $\cdot \mathrm{AlH}_{2} \mathrm{AsH}_{2}$ (4) can be isolated at $-30^{\circ} \mathrm{C}$ as colorless plates in a yield of $40 \%$ via route 1 . The LIFDI-MS spectrum of $\mathbf{4}$ only shows the fragment ion peak of IDipp $^{+}$due to the decomposition of $\mathbf{4}$ during the ionization process. The ${ }^{1} \mathrm{H}$ NMR spectrum of 4 in $\mathrm{C}_{6} \mathrm{D}_{6}$ reveals a triplet at $\delta=$
$-0.47 \mathrm{ppm}\left({ }^{3} J_{\mathrm{H}, \mathrm{H}}=3.23 \mathrm{~Hz}\right)$ for the $\mathrm{AsH}_{2}$ moiety and a broad singlet at $\delta=4.1 \mathrm{ppm}$ for the $\mathrm{AlH}_{2}$ moiety. In the ${ }^{1} \mathrm{H}$ NMR spectrum, besides 4 a side product IDipp $\cdot \mathrm{AlH}\left(\mathrm{AsH}_{2}\right)_{2}(\mathbf{5})$ can be detected as two doublets of doublets at $\delta=-0.15 \mathrm{ppm}$ and $\delta=-0.04 \mathrm{ppm}$, respectively, for the $\mathrm{AsH}_{2}$ moieties $\left({ }^{2} J_{\mathrm{H}, \mathrm{H}}=\right.$ $12.59 \mathrm{~Hz},{ }^{3} J_{\mathrm{H}, \mathrm{H}}=2.80 \mathrm{~Hz}$ ). The signals for these two $\mathrm{AsH}_{2}$ moieties split in two separated signals because of the prochirality of the entities. The ${ }^{27} \mathrm{Al}$ NMR spectrum of 4 shows a broad signal at $\delta=133.5 \mathrm{ppm}$ which is partly superimposed with the signal of the NMR sample head and the NMR tube material. Compound 4 (Figure 4) crystallizes in the monoclinic space group $I 2 / a$ and co-crystallizes with IDipp $\cdot \mathrm{AlH}\left(\mathrm{AsH}_{2}\right)_{2}(5)$ (for more information, see SI). The Al-As distance in $\mathbf{4}$ is in the range of 2.399(6)-2.473(4) $\AA$. The $\mathrm{Al}-\mathrm{C} 1$ bond length $(2.060(2) \AA$ ) is very similar to the bond length in $\mathbf{1}(2.0634(12) \AA)$ and IDipp• $\mathrm{AlH}_{2} \mathrm{PH}_{2}(2.056-$ (2) $\AA) .{ }^{[7]}$ The C1-Al-As angle varies between $107.83(17)^{\circ}$ and 114.3(2) ${ }^{\circ}$ because of the disorder of the $\mathrm{AsH}_{2}$ moiety.

The formation of IDipp• $\mathrm{AlH}\left(\mathrm{AsH}_{2}\right)_{2}(\mathbf{5})$ as a side product led us to the question if the selective synthesis of compounds of the type IDipp• $\mathrm{E}^{\prime} \mathrm{H}\left(\mathrm{AsH}_{2}\right)_{2}\left(\mathrm{E}^{\prime}=\mathrm{Al}, \mathrm{Ga}\right)$ was possible, and indeed we were able to synthesize 5 and IDipp. $\mathrm{GaH}\left(\mathrm{AsH}_{2}\right)_{2}$


Figure 4. Molecular structure of 4 in solid state (part 1); thermal ellipsoids at $50 \%$ probability. ${ }^{[19]}$ Selected bond lengths $[\AA \AA]$ and angles [ ${ }^{\circ}$ ]: Al-As1 2.399(6), C1-Al 2.060(2), C1-Al-As1 107.83(17)-114.3(2).
(6) via the corresponding salt metathesis route [Eq. (3)], which was supported by DFT computations (see Table 1, process 10 ). In fact, such branched alkane-like parent compounds are so far unknown and only additional donor stabilized compounds of the type ( $\mathrm{Dipp}_{2} \mathrm{Nacnac}^{\prime} \mathrm{E}^{\prime}\left(\mathrm{EH}_{2}\right)_{2}$ $\left(\right.$ Dipp $_{2}$ Nacnac $\left.=\mathrm{HC}[\mathrm{C}(\mathrm{Me}) \mathrm{N}(\mathrm{Ar})]_{2}, \mathrm{Ar}=2,6-i \mathrm{Pr}_{2} \mathrm{C}_{6} \mathrm{H}_{3}\right)$ exist for $\mathrm{E}=\mathrm{N},{ }^{[16 a]} \mathrm{P}$, As. ${ }^{[16 \mathrm{~b}]}$

(3)

Compounds $\mathbf{5}$ and $\mathbf{6}$ crystallize as colorless thin needles at $-30^{\circ} \mathrm{C}$ in a yield of $42 \%$ and $36 \%$, respectively. The LIFDIMS spectrum of $\mathbf{5}$ shows a fragment ion peak of IDipp ${ }^{+}$due to decomposition of $\mathbf{5}$ during the ionization process. In the mass spectrum of 6 (LIFDI-MS) the molecular ion peak is detected at $m / z 611.0607[M-H]^{+}$. Solutions of 5 show a strong tendency towards decomposition. The ${ }^{1} \mathrm{H}$ NMR spectrum of 5 in $\left[\mathrm{D}_{8}\right]$ toluene at $-80^{\circ} \mathrm{C}$ reveals two doublets of doublets at $\delta=-0.09 \mathrm{ppm}$ and $\delta=0.14 \mathrm{ppm} \quad\left({ }^{2} J_{\mathrm{H}, \mathrm{H}}=12.40 \mathrm{~Hz},{ }^{3} J_{\mathrm{H}, \mathrm{H}}=\right.$ 2.71 Hz ) for the two $\mathrm{AsH}_{2}$ moieties, a broad singlet at $\delta=$ 4.82 ppm for the AlH moiety, as well as the formation of IDippH $H_{2}$ and free IDipp as decomposition products. In the ${ }^{1} \mathrm{H}$ NMR spectrum of 6 in $\mathrm{C}_{6} \mathrm{D}_{6}$ the signals for the $\mathrm{AsH}_{2}$ moieties and the GaH moiety are shifted downfield to $\delta=$ $0.20,0.38\left({ }^{2} J_{\mathrm{H}, \mathrm{H}}=12.77 \mathrm{~Hz},{ }^{3} J_{\mathrm{H}, \mathrm{H}}=3.46 \mathrm{~Hz}\right)$, and $\delta=5.09 \mathrm{ppm}$ compared to 5 .

Compounds 5 and 6 crystallize from concentrated $n$ hexane solutions as very thin colorless plates. Because of the thinness of the crystals the single-crystal X-ray analysis of 6 was only possible to a theta range of $47^{\circ}$. Nevertheless, it was possible to solve the structure and prove the framework of the heavy atoms of $\mathbf{6}$ (see Figure S42). Compound 5 co-crystallizes with $6 \%$ of the starting material IDipp $\cdot \mathrm{AlHCl}_{2}$ (see Figure S41). Compounds $\mathbf{5}$ and $\mathbf{6}$ crystallize in the monoclinic space group $I 2 / a$. The molecular structure of $\mathbf{5}$ in solid state is depicted in Figure 5. The E'-As distances in $\mathbf{5}$ and $\mathbf{6}$ are in the range of $2.451(4)-2.511(6) \AA(5)$ and $2.4412(19)-2.446(2) \AA$ (6), respectively, and therefore similar to the $\mathrm{Al}-\mathrm{As}$ bonds in $\left(\right.$ Dipp $\left._{2} \mathrm{Nacnac}\right) \mathrm{Al}\left(\mathrm{AsH}_{2}\right)_{2} \quad\left(\mathrm{Dipp}_{2} \mathrm{Nacnac}=\mathrm{HC}[\mathrm{C}(\mathrm{Me}) \mathrm{N}-\right.$ (Ar) $\left.]_{2}, \mathrm{Ar}=2,6-\mathrm{Pr}_{2} \mathrm{C}_{6} \mathrm{H}_{3}\right) .{ }^{[15]}$ The $\mathrm{E}^{\prime}-\mathrm{C} 1$ bond lengths ( $\mathrm{Al}-$ $\mathrm{C} 1=2.066(3) \AA, \mathrm{Ga}-\mathrm{C} 1=2.064(9) \AA)$ are not heavily affected by the presence of a second $\mathrm{AsH}_{2}$ moiety compared to 3 (2.0476(17) $\AA$ ) and $4(2.060(2) \AA)$, respectively. The C1-E'-As angles are $114.24(9)^{\circ}$ and $114.38(10)^{\circ}$ for $\mathbf{5}$ as well as $111.7(2)^{\circ}$ and $113.3(2)^{\circ}$ for $\mathbf{6}^{[17]}$

Interestingly, during the synthesis of the phosphorus analog IDipp $\cdot \mathrm{E}^{\prime} \mathrm{H}_{2} \mathrm{PH}_{2}\left(\mathrm{E}^{\prime}=\mathrm{Al}, \mathrm{Ga}\right)$ by the reaction of IDipp• $\mathrm{E}^{\prime} \mathrm{H}_{2} \mathrm{Cl}$ with $\mathrm{NaPH}_{2}$ we did not find any sign for the formation of IDipp $\cdot \mathrm{E}^{\prime} \mathrm{H}\left(\mathrm{PH}_{2}\right)_{2}\left(\mathrm{E}^{\prime}=\mathrm{Al}, \mathrm{Ga}\right)$ as a side product. ${ }^{[7]}$ A possible pathway for the formation of $\mathbf{5}$ as a side product in the arsenic case is the reaction of the formed product IDipp. $\mathrm{E}^{\prime} \mathrm{H}_{2} \mathrm{AsH}_{2}$ with in situ formed $\mathrm{AsH}_{3}$ in an $\mathrm{H}_{2}-$ elimination reaction. Computations confirm that this route is


Figure 5. Molecular structure of $\mathbf{5}$ in solid state; thermal ellipsoids at $50 \%$ probability. ${ }^{[19]}$ Selected bond lengths [Å] and angles [ ${ }^{\circ}$ ]: Al-As 1 2.451 (4), Al-As2 2.474(3), Al-Cl 2.066(3), As1-Al-C1 114.38(10), As2-AlC1 114.24(9).
possible in the arsenic case (Table 1, process 7) while it is more unlikely for phosphorus (Table 1, process 8), which agrees with our experimental observations.

Similar to 5 and $\mathbf{6}$, we were able to synthesize the parent branched compounds IDipp•GaH $\left(\mathrm{PH}_{2}\right)_{2}(7)$ and IDipp•AlH$\left(\mathrm{PH}_{2}\right)_{2}$ (8) selectively by the salt metathesis reaction of IDipp $\cdot \mathrm{E}^{\prime} \mathrm{HCl}_{2}$ and $\mathrm{NaPH}_{2}$ in $\mathrm{Et}_{2} \mathrm{O}$ (Table 1, process 9). Compounds $\mathbf{7}$ and $\mathbf{8}$ can be isolated at $-30^{\circ} \mathrm{C}$ in a yield of $57 \%$ and $48 \%$, respectively. The ${ }^{1} \mathrm{H}$ NMR spectrum of 7 in $\mathrm{C}_{6} \mathrm{D}_{6}$ shows a doublet which splits into multipletts at $\delta=$ $0.54 \mathrm{ppm}\left({ }^{1} J_{\mathrm{P}, \mathrm{H}}=175 \mathrm{~Hz}\right.$ ) for the $\mathrm{PH}_{2}$ moieties and a broad singlet at $\delta=4.81 \mathrm{ppm}$ for the GaH moiety. In the ${ }^{1} \mathrm{H}$ NMR spectrum of $\mathbf{8}$ in $\left[\mathrm{D}_{8}\right]$ toluene at $-80^{\circ} \mathrm{C}$ the $\mathrm{PH}_{2}$ moieties can be detected at $\delta=0.42 \mathrm{ppm}\left({ }^{1} J_{\mathrm{P}, \mathrm{H}}=175.4 \mathrm{~Hz}\right)$ as a doublet of multiplets. The AlH moiety can be detected as a broad singlet at $\delta=4.56 \mathrm{ppm}$. The ${ }^{31} \mathrm{P}$ NMR spectra of $\mathbf{7}$ and $\mathbf{8}$ show a triplet of multiplets at $\delta=-255.4 \mathrm{ppm}\left(7,{ }^{1} J_{\mathrm{P}, \mathrm{H}}=175 \mathrm{~Hz}\right.$, $\left.{ }^{2} J_{\mathrm{P}, \mathrm{H}}=18.17 \mathrm{~Hz}\right)$ and at $\delta=-270.8 \mathrm{ppm}\left(8,{ }^{1} J_{\mathrm{P}, \mathrm{H}}=175.4 \mathrm{~Hz}\right.$, $\left.{ }^{2} J_{\mathrm{P}, \mathrm{H}}=15.48 \mathrm{~Hz}\right)$, respectively. Due to the prochirality of the $\mathrm{PH}_{2}$ groups in 7 and 8 the signals in the ${ }^{1} \mathrm{H}$ and ${ }^{31} \mathrm{P}$ NMR spectra reveal a fine splitting which could not be resolved. Like 5, solutions of $\mathbf{8}$ show a strong tendency towards decomposition. Compounds $\mathbf{7}$ and $\mathbf{8}$ crystallize in the monoclinic space group $I 2 / a$. The molecular structures of $\mathbf{7}$ and $\mathbf{8}$ in solid state are shown in Figure 6 and Figure S44, respectively. The $\mathrm{E}^{\prime}-\mathrm{P}$ bonds are shorter compared to the arsenic analogs with $2.3437(10)-2.3574(9) \AA(7)$ and $2.3075(10)-2.3418(9) \AA$ (8). The $\mathrm{E}^{\prime}-\mathrm{C} 1$ bond lengths are again not affected by the change from arsenic substituents to phosphorus substituents on the $\mathrm{E}^{\prime}$ atom. The $\mathrm{Ga}-\mathrm{C} 1$ bond length is $2.075(3) \AA$ and the $\mathrm{Al}-\mathrm{C} 1$ bond length is $2.066(2) \AA$. The $\mathrm{C} 1-\mathrm{E}^{\prime}-\mathrm{P}$ angles (112.38(7) ${ }^{\circ}$ and $113.68(7)^{\circ}$ for 7; 112.04(6) ${ }^{\circ}$ and $113.91(6)^{\circ}$ for $\mathbf{8}$ ) are comparable to the $\mathrm{C} 1-\mathrm{E}^{\prime}-\mathrm{As}$ angles in the arsenic analogs 5 and 6.

Computational studies indicate that the salt elimination route via solid potassium chloride formation is highly exothermic and exergonic both for the parent and the substituted compounds, which could be experimentally verified by the synthesis of $\mathbf{1 - 4}$. (Table 1, process 3 and 4). The hydrogen elimination route via the reaction of IDipp• $\cdot \mathrm{E}^{\prime} \mathrm{H}_{3}$


Figure 6. Molecular structure of 7 in solid state; thermal ellipsoids at $50 \%$ probability. ${ }^{[19]}$ Selected bond lengths $[\AA \AA]$ and angles [ $\left.{ }^{\circ}\right]$ : Ga-P1 2.3574 (9), Ga-P2 2.3437(10), Ga-C1 2.075(3), P1-Ga-C1 113.68(7), P2-Ga-C1 112.38(7).
with $\mathrm{AsH}_{3}$ (Table 1, process 1) is exothermic and at 298 K exergonic by about $20 \mathrm{~kJ} \mathrm{~mol}^{-1}$, but slightly endergonic (2$7 \mathrm{~kJ} \mathrm{~mol}^{-1}$ ) for the reaction with diphenylarsine (Table 1, process 2 ), which reflects that compounds $\mathbf{1}$ and $\mathbf{2}$ could not be accessed via route 2 . Compounds $\mathbf{1 - 4}$ are predicted to be stable with respect to IDipp dissociation with formation of $\left(\mathrm{E}^{\prime} \mathrm{H}_{2} \mathrm{AsH}_{2}\right)_{n}$ polymers, which were modeled by the formation of the trimer ${ }^{[18]}$ (Table 1, process 5 and 6). The interaction of IDipp $\cdot \mathrm{E}^{\prime} \mathrm{H}_{2} \mathrm{AsH}_{2}$ with an arsine formed in situ (Table 1, process 7) is also exergonic ( $\mathrm{Al}:-10.1 \mathrm{~kJ} \mathrm{~mol}^{-1}$, Ga : $-13.8 \mathrm{~kJ} \mathrm{~mol}^{-1}$ ) and may explain the formation of $\mathbf{5}$ as a side product during the synthesis of IDipp• $\mathrm{AlH}_{2} \mathrm{AsH}_{2}$ via route 1 . In contrast, a similar reaction for the phosphorus analogs (Table 1, process 8) is energetically less favored and has Gibbs energies close to zero at 298 K. Nevertheless, computations show that route 1 is an even more exergonic reaction for the synthesis of branched pnictogenylalanes and -gallanes than for the synthesis of the linear compounds (Table 1, process 9 and 10). This is confirmed by the synthesis of the unique molecules IDipp•E'H(AsH $)_{2}$ (5: Al, 6: Ga) and IDipp• $\mathrm{E}^{\prime} \mathrm{H}\left(\mathrm{PH}_{2}\right)_{2}(7: \mathrm{Ga}, 8: \mathrm{Al})$ via route 1 .

## Conclusion

The results show that, regardless of the rather low $\mathrm{E}^{\prime}$-As bond stability $\left(\mathrm{E}^{\prime}=\mathrm{Al}, \mathrm{Ga}\right)$, we succeeded in the synthesis of the first monomeric parent arsanylalanes and -gallanes stabilized only by a LB. Besides the synthesis of the organosubstituted arsenic derivatives by salt metathesis, it was shown that the monomeric parent compounds can be obtained by salt metathesis and $\mathrm{H}_{2}$-eliminations, respectively. However, the latter method is incomplete, so that the first one is preferred. Furthermore, in contrast to the synthesis of the corresponding phosphanylalanes and -gallanes, the As derivatives exhibit a different reactivity and form the branched side products IDipp $\cdot \mathrm{E}^{\prime} \mathrm{H}\left(\mathrm{AsH}_{2}\right)_{2}\left(\mathrm{E}^{\prime}=\mathrm{Al}, \mathrm{Ga}\right)$, obviously by $\mathrm{AsH}_{3}$-caused substitution reactions. This kind of alkane-like branched parent derivatives had been unknown before and subsequently the double substituted parent compounds

IDipp $\cdot \mathrm{E}^{\prime} \mathrm{H}\left(\mathrm{EH}_{2}\right)_{2}\left(\mathrm{E}^{\prime}=\mathrm{Al}, \mathrm{Ga} ; \mathrm{E}=\mathrm{As}, \mathrm{P}\right)$ could be selectively synthesized by salt metathesis reactions. They may serve as chelating ligands in coordination chemistry, which is currently being investigated. The monomeric compounds IDipp $\cdot \mathrm{E}^{\prime} \mathrm{H}_{2} \mathrm{AsH}_{2} \quad\left(\mathrm{E}^{\prime}=\mathrm{Al}, \mathrm{Ga}\right)$ represent unprecedented parent arsanylalanes and -gallanes without any prior sterical stabilization by a substituent but by a LB. In further studies, the focus will be on their reaction behavior towards catenation and as precursor for CVD processes to obtain Group 13/15 materials.

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## Conflict of interest

The authors declare no conflict of interest.
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